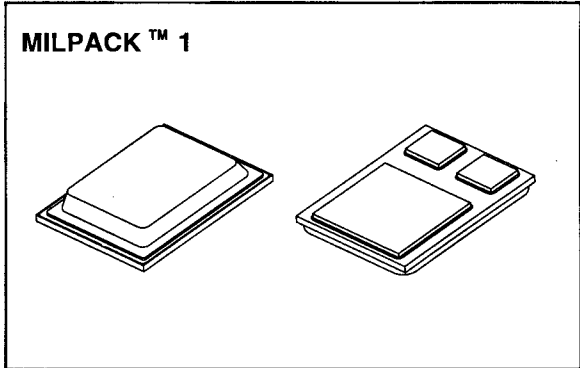


**SDR950E
 thru
 SDR952E**

**60 AMP
 100-200 VOLTS
 35 nsec
 HYPER FAST
 RECTIFIER**



Designer's Data Sheet

- FEATURES:**
- Hyper Fast Recovery: 35 nsec Maximum
 - High Surge Rating
 - Low Reverse Leakage Current
 - Low Junction Capacitance
 - Hermetically Sealed Surface Mount Package
 - Gold Eutectic Die Attach available
 - Ultrasonic Aluminum Wire Bonds
- TX, TXV and Space Level Screening Available

MAXIMUM RATINGS

RATING	SYMBOL	VALUE	UNIT
Peak Repetitive Reverse and DC Blocking Voltage	VRRM VRWM VR	100 150 200	Volts
Average Rectified Forward Current (Resistive Load, 60Hz, Sine Wave, TA=25°C)	Io	60	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave, TA=25°C) note 1	IFSM	600	Amps
Operating and storage temperature	Top & Tstg	-65 to +200	°C
Maximum Thermal Resistance Junction to Case	RθJC	0.8	°C/W

note 1 Connect pins 2 & 3 together

SDR950E thru SDR952E

PRELIMINARY

SSDI
SOLID STATE DEVICES, INC

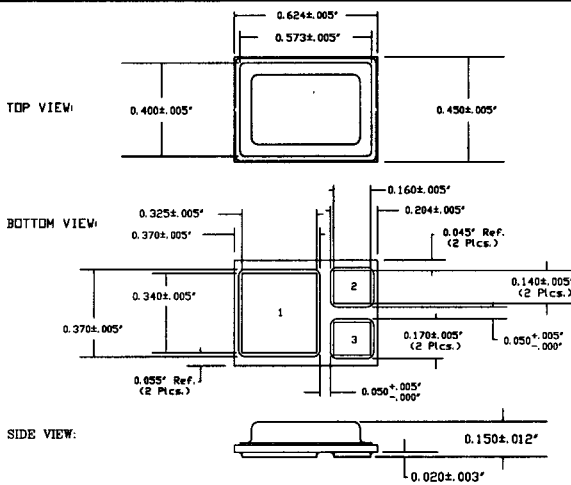
14849 Firestone Boulevard · La Mirada, CA 90638
Phone: (714) 670-SSDI (7734) · Fax: (714) 522-7424

ELECTRICAL CHARACTERISTICS

CHARACTERISTICS	SYMBOL	MAXIMUM	UNIT
Instantaneous Forward Voltage Drop (IF = 25 Adc, TA=25°C, 300µs Pulse) (IF = 50 Adc, TA=25°C, 300µs Pulse)	VF	0.95 1.05	Vdc
Instantaneous Forward Voltage Drop (IF = 50 Adc, TA= 100°C, 300µs Pulse) (IF = 25 Adc, TA= - 55°C, 300µs Pulse)	VF	0.85 1.20	Vdc
Reverse Leakage Current (Rated VR, TA=25°C, 300µs pulse minimum)	IR	100	µA
Reverse Leakage Current (Rated VR, TA=100°C, 300µs pulse minimum)	IR	10	mA
Junction Capacitance (VR = 10 Vdc, TA=25°C, f= 1 MHz)	CJ	450	pf
Reverse Recovery Time (IF=500mA, IR=1 A, IRR=250mA, TA=25°C)	trr	35	nsec

CASE OUTLINE: MILPACK

PIN 1: CATHODE
PIN 2: ANODE
PIN 3: ANODE



Note: Tolerances are ±.005" unless otherwise specified.

TYPICAL OPERATING CURVES

TA=25°C Unless otherwise specified

